

Refine Search

Search Results -

Terms	Documents
L9 and L10	0

Database:
 US Pre-Grant Publication Full-Text Database
 US Patents Full-Text Database
 US OCR Full-Text Database
 EPO Abstracts Database
 JPO Abstracts Database
 Derwent World Patents Index
 IBM Technical Disclosure Bulletins

L11
Search:

Refine Search

Recall Text

Clear

Interrupt

Search History

DATE: Tuesday, July 03, 2007 [Purge Queries](#) [Printable Copy](#) [Create Case](#)

Set Name	Query	Hit Count	Set Name
side by side			result set
<i>DB=PGPB,USPT,USOC,EPAB,JPAB,DWPI,TDBD; PLUR=YES; OP=ADJ</i>			
<u>L11</u>	l9 and L10	0	<u>L11</u>
<u>L10</u>	transistor same conduct\$3 current	17811	<u>L10</u>
<u>L9</u>	l7 and L8	15	<u>L9</u>
<u>L8</u>	discharg\$3 same time interval	25153	<u>L8</u>
<u>L7</u>	l5 and L6	288	<u>L7</u>
<u>L6</u>	current source	188267	<u>L6</u>
<u>L5</u>	l3 and L4	1818	<u>L5</u>
<u>L4</u>	transistor and discharg\$3	157385	<u>L4</u>
<u>L3</u>	l1 and L2	10826	<u>L3</u>
<u>L2</u>	capacitor	799274	<u>L2</u>
<u>L1</u>	physical player or phy	130808	<u>L1</u>

END OF SEARCH HISTORY

Freeform Search

US Pre-Grant Publication Full-Text Database
US Patents Full-Text Database
US OCR Full-Text Database
Database: EPO Abstracts Database
JPO Abstracts Database
Derwent World Patents Index
IBM Technical Disclosure Bulletins

13 and L7

Term:

Display: 10 | **Documents in Display Format:** - | **Starting with Number** 1

Generate: Hit List Hit Count Side by Side Image

Search

Clear

Interrupt

Search History

DATE: Tuesday, July 03, 2007 [Purge Queries](#) [Printable Copy](#) [Create Case](#)

Set Name	Query	Hit Count	Set Name
result set			
<u>L8</u>	l3 and L7	1	<u>L8</u>
<u>L7</u>	transistor same conduction current	2321	<u>L7</u>
<u>L6</u>	l1 and L5	0	<u>L6</u>
<u>L5</u>	discharg\$3 same time interval	25153	<u>L5</u>
<u>L4</u>	l1 and L3	0	<u>L4</u>
<u>L3</u>	discharg\$3 time interval	421	<u>L3</u>
<u>L2</u>	4992674.bn.	2	<u>L2</u>
<u>L1</u>	4992674	17	<u>L1</u>

END OF SEARCH HISTORY

"INTERFERENT"
Refine Search

Search Results -

Terms	Documents
(transistor same discharge current same time interval same substantially equal same first portion) and (second current source same discharge current same less than same transistor conductio current)	0

Database: US Pre-Grant Publication Full-Text Database
 US Patents Full-Text Database
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 IBM Technical Disclosure Bulletins

L1
Search:

Search History

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Set
Name Query
 side by
 side

Hit
Count Set
 result
 set

DB=PGPB; PLUR=YES; OP=ADJ

L1 (transistor same discharge current same time interval same substantially equal
 same first portion) and (second current source same discharge current same
 less than same transistor conductio current)

0 L1

END OF SEARCH HISTORY